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1. (Previously Presented) A reflective-type liquid crystal display comprising:  
a first-type electrode;  
a second-type electrode positioned opposite said first-type electrode and being of an opposite type than said first-type electrode; and  
a liquid crystal material between said first-type electrode and said second-type electrode,  
wherein at least one of said first-type electrode and said second-type electrode includes a conducting amorphous layer adjacent said liquid crystal material, wherein said conducting amorphous layer has a resistivity between  $10^4$  and  $10^{11}$  ohms-cm.
2. (Original) The reflective-type liquid crystal display in claim 1, wherein said first-type electrode comprises a transmissive-type electrode and said second-type electrode comprises a reflective-type electrode.
3. (Previously Presented) A reflective-type liquid crystal display comprising:  
a first-type electrode;  
a second-type electrode positioned opposite said first-type electrode and being of an opposite type than said first-type electrode; and  
a liquid crystal material between said first-type electrode and said second-type electrode,  
wherein at least one of said first-type electrode and said second-type electrode includes a conducting amorphous layer adjacent said liquid crystal material, wherein said conducting amorphous layer has a resistivity between  $10^4$  and  $10^{11}$  ohms-cm, and  
wherein said amorphous layer comprises one of a hydrogenated amorphous carbon silicon, germanium,  $\text{SiO}_2$ ,  $\text{Si}_3\text{N}_4$  and  $\text{TiO}_2$ .
4. (Original) The reflective-type liquid crystal display in claim 1, wherein said amorphous layer has a unidirectional orientation matched to said liquid crystal material.

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5. (Original) The reflective-type liquid crystal display in claim 1, further comprising one of a polyimide layer, polyamide layer and oblique-evaporated inorganic layer between said amorphous layer and said liquid crystal material.

6. (Original) The reflective-type liquid crystal display in claim 1, wherein a voltage between said first-type electrode and said reflective electrode varies a transparency of said liquid crystal material.

7. (Original) The reflective-type liquid crystal display in claim 1, wherein said amorphous layer comprises a passivation layer.

8. (Previously Presented) A reflective-type liquid crystal display comprising:  
a transmissive electrode;  
a reflective electrode positioned opposite said transmissive electrode; and  
a liquid crystal material between said transmissive electrode and said reflective electrode,  
wherein at least one of said transmissive electrode and said reflective electrode includes a conducting diamond-like amorphous carbon layer adjacent said liquid crystal material, wherein said diamond-like conducting amorphous carbon layer has a resistivity between  $10^4$  and  $10^{11}$  ohms-cm.

9. (Original) The reflective-type liquid crystal display in claim 8, wherein said transmissive electrode comprises indium tin oxide and said reflective-type electrode comprises aluminum.

10. (Previously Presented) A reflective-type liquid crystal display comprising:  
a transmissive electrode;  
a reflective electrode positioned opposite said transmissive electrode; and  
a liquid crystal material between said transmissive electrode and said reflective electrode,

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wherein at least one of said transmissive electrode and said reflective electrode includes a conducting diamond-like amorphous carbon layer adjacent said liquid crystal material, wherein said diamond-like conducting amorphous carbon layer has a resistivity between  $10^4$  and  $10^{11}$  ohms-cm, and

wherein said amorphous carbon layer comprises one of a hydrogenated amorphous carbon silicon, germanium,  $\text{SiO}_2$ ,  $\text{Si}_3\text{N}_4$  and  $\text{TiO}_2$ .

11. (Original) The reflective-type liquid crystal display in claim 8, wherein said amorphous carbon layer has a unidirectional orientation matched to said liquid crystal material.

12. (Original) The reflective-type liquid crystal display in claim 8, further comprising one of a polyimide layer, polyamide layer and oblique-evaporated inorganic layer between said amorphous carbon layer and said liquid crystal material.

13. (Original) The reflective-type liquid crystal display in claim 8, wherein a voltage between said transmissive electrode and said reflective electrode varies a transparency of said liquid crystal material.

14. (Original) The reflective-type liquid crystal display in claim 8, wherein said amorphous carbon layer comprises a passivation layer.

15. (Previously Presented) A method of forming a reflective-type liquid crystal display comprising:

forming a first-type electrode;

forming a second-type electrode positioned opposite said first-type electrode and being of an opposite type than said first-type electrode;

forming a liquid crystal material between said first-type electrode and said second-type electrode; and

forming a conducting amorphous layer on at least one of said first-type electrode and said second-type electrode adjacent said liquid crystal material, wherein said

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conducting amorphous layer is formed to have a resistivity between  $10^4$  and  $10^{11}$  ohms-cm.

16. (Original) The method in claim 15, wherein said forming of said first-type electrode comprises forming a transmissive-type electrode and said forming of said second-type electrode comprises forming a reflective-type electrode.

17. (Previously Presented) A method of forming a reflective-type liquid crystal display comprising:

- forming a first-type electrode;

- forming a second-type electrode positioned opposite said first-type electrode and being of an opposite type than said first-type electrode;

- forming a liquid crystal material between said first-type electrode and said second-type electrode; and

- forming a conducting amorphous layer on at least one of said first-type electrode and said second-type electrode adjacent said liquid crystal material, wherein said conducting amorphous layer is formed to have a resistivity between  $10^4$  and  $10^{11}$  ohms-cm, and

- wherein said forming of said amorphous layer comprises forming one of a hydrogenated amorphous carbon silicon, germanium,  $\text{SiO}_2$ ,  $\text{Si}_3\text{N}_4$  and  $\text{TiO}_2$  layer.

18. (Original) The method in claim 15, wherein method includes forming said amorphous layer to have a unidirectional orientation matched to said liquid crystal material.

19. (Original) The method in claim 15, further comprising forming one of a polyimide layer, polyamide layer and oblique-evaporated inorganic layer between said amorphous layer and said liquid crystal material.

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20. (Original) The method in claim 15, wherein a voltage between said first-type electrode and said reflective electrode varies a transparency of said liquid crystal material.